

### General Description

SDC11170 is a single-phase full-wave driver for fan motor. It features a variable speed control method using both PWM input and thermistor and a high-efficiency driver architecture. An external filter is introduced to reduce the vibration and acoustic noise. SDC11170 is ideal for a quiet and high-efficiency cooler fan.

### Applications

- CPU cooler fan motor

### Features

- Single-phase full-wave drive(18V~1.2A output transistor incorporated)
- Triangular wave oscillation voltage and minimum speed settable
- 6V , Hall bias and FG output
- Kick-back absorption circuit incorporated
- Ineffective current reduced during phase shift
- Regeneration diodes incorporated with less external parts

### Pin Configuration

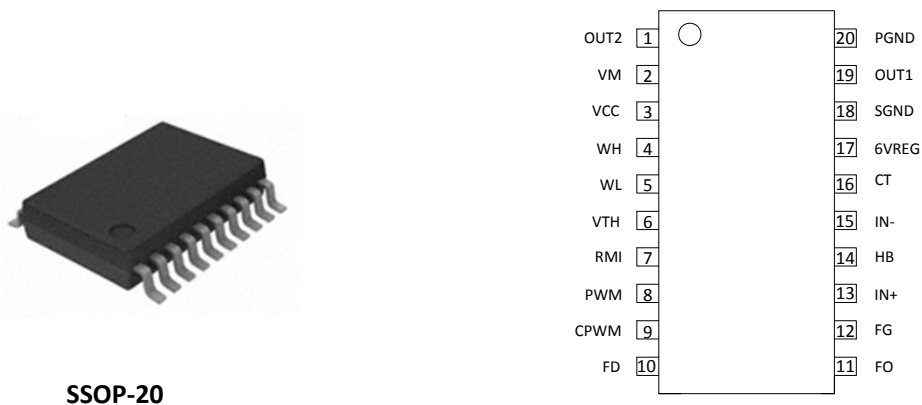


Figure 1. Pin Configuration

| Pin Number | Pin Name | Function                                  |
|------------|----------|---|
| 1          | OUT2     | Output 2                                  |
| 2          | VM       | Motor power                               |
| 3          | VCC      | Chip power                                |
| 4          | WH       | Triangular wave oscillation upper voltage |
| 5          | WL       | Triangular wave oscillation lower voltage |
| 6          | VTH      | Thermistor input                          |
| 7          | RMI      | Minimum pulse width setting               |
| 8          | PWM      | PWM input                                 |
| 9          | CPWM     | Triangular wave oscillation capacitor     |
| 10         | FD       | External filter driver                    |

| Pin Number | Pin Name | Function                 |
|------------|----------|--------------------------|
| 11         | FO       | External filter output   |
| 12         | FG       | Frequency generation     |
| 13         | IN+      | Positive hall signal     |
| 14         | HB       | Hall bias                |
| 15         | IN-      | Negative hall signal     |
| 16         | CT       | Lock detection capacitor |
| 17         | 6VREG    | 6V regulator output      |
| 18         | S-GND    | Signal GND               |
| 19         | OUT1     | Output 1                 |
| 20         | P-GND    | Power GND                |

Table 1. Pin Description

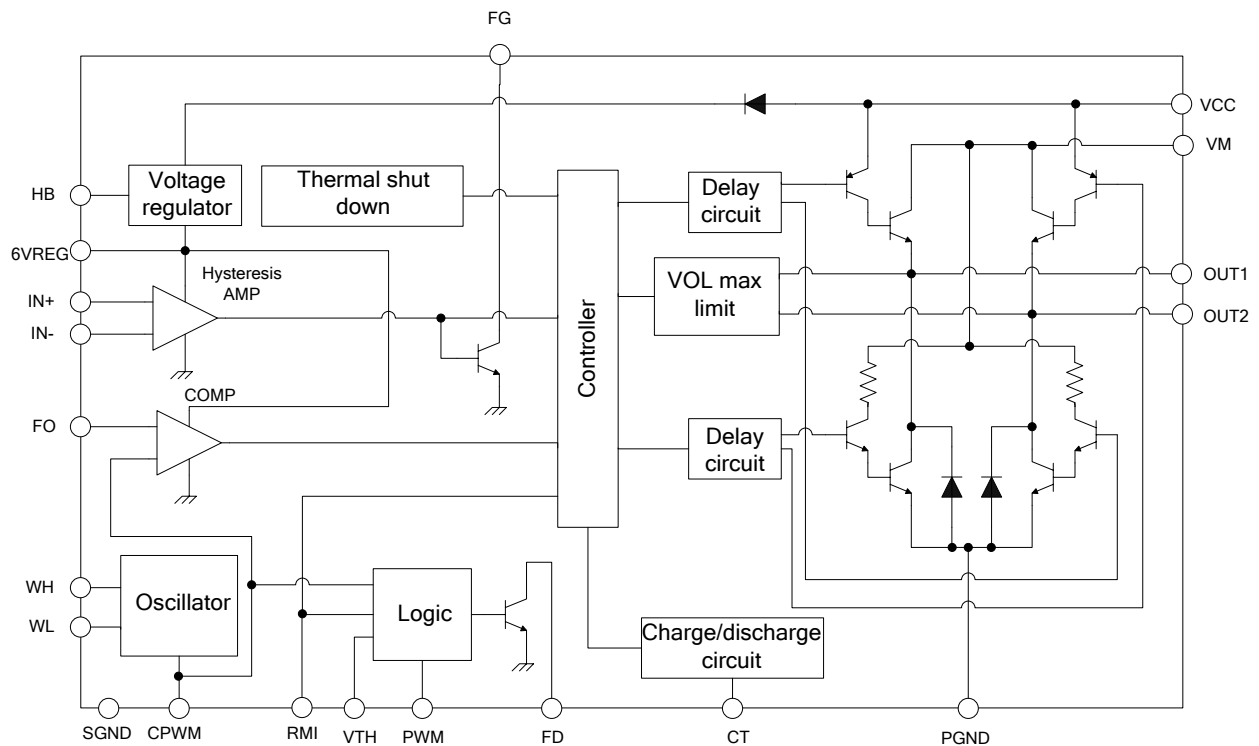
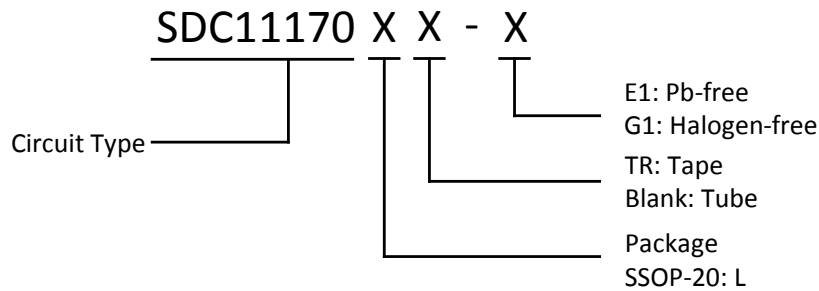
**Functional Block Diagram**


Figure 2. Functional Block Diagram

**Ordering Information**


| Package | Temperature Range | Part Number    |                | Marking ID |              | Packing Type |
|---------|-------------------|----------------|----------------|------------|--------------|--------------|
|         |                   | Pb-free        | Halogen-free   | Pb-free    | Halogen-free |              |
| SSOP-20 | -30°C~95°C        | SDC11170LTR-E1 | SDC11170LTR-G1 | SDC11170   | SDC11170-G   | Tape         |
|         |                   | SDC11170L-E1   | SDC11170L-G1   | SDC11170   | SDC11170-G   | Tube         |

**Absolute Maximum Ratings** (Note: Stresses greater than those listed under Absolute Maximum Ratings may cause permanent damage to the device.)

| Parameter                               | Symbol         | Conditions | Min  | Max      | Unit |
|---|----------------|------------|------|----------|------|
| VCC maximum supply voltage              | $V_{CCMAX}$    | -          | -    | 17       | V    |
| VM maximum supply voltage               | $V_{MMAX}$     | -          | -    | $V_{CC}$ | V    |
| OUT pin maximum output current          | $I_{OUTMAX}$   | -          | -    | 1.2      | A    |
| OUT pin maximum withstand voltage       | $V_{OUTMAX}$   | -          | -    | 18       | V    |
| PGND to SGND voltage                    |                | -          | -0.3 | 0.3      | V    |
| HB pin maximum output current           | $I_{HBMAX}$    | -          | -    | 10       | mA   |
| VTH, RMI, PWM, FO pin withstand voltage | $V_{THMAX}$    | -          | -    | 7.0      | V    |
| FG pin withstand voltage                | $V_{FGMAX}$    | -          | -    | 18       | V    |
| 6VREG pin output source current         | $I_{6VREGMAX}$ | -          | -    | 10       | mA   |
| FG output current                       | $I_{FGMAX}$    | -          | -    | 10       | mA   |
| Allowable power dissipation             | $Pd_{MAX}$     | -          | -    | 0.8      | W    |
| Operating temperature range             | $T_{OPR}$      | -          | -30  | 95       | °C   |
| Storage temperature range               | $T_{STG}$      | -          | -55  | 150      | °C   |

Table 2. Absolute Maximum Ratings

**Recommend Operating Conditions**

| Parameter                                   | Symbol     | Conditions | Min | Max      | Unit |
|---|------------|------------|-----|----------|------|
| VCC supply voltage                          | $V_{CC}$   | -          | 4.5 | 16       | V    |
| VM supply voltage                           | $V_M$      | -          | 3.5 | $V_{CC}$ | V    |
| VTH、RMI、PWM、FO input voltage range          | $V_{TH}$   | -          | 0   | 6.0      | V    |
| Triangular wave input range                 | $V_{CPWM}$ | -          | 0.5 | 4.0      | V    |
| HALL input common-phase input voltage range | $V_{ICM}$  | -          | 0.2 | 3.0      | V    |

Table 3. Commended Operating Conditions

**Electrical Characteristics** ( $T_a=25^{\circ}C$ ,  $V_{CC}=12V$ , unless otherwise specified)

| Parameter                         | Symbol      | Conditions                      | Min  | Typ      | Max      | Unit        |
|-----------------------------------|-------------|---------------------------------|------|----------|----------|-------------|
| Supply current                    | $I_{CC1}$   | During drive                    | 17   | 20       | 23       | mA          |
|                                   | $I_{CC2}$   | During lock protection          | -    | 7        | 10       | mA          |
| HB voltage                        | $V_{HB}$    | $I_{HB}=-5mA$                   | 1.1  | 1.25     | 1.4      | V           |
| 6V voltage                        | $6V_{REG}$  | $I_{6VREG}=-5mA$                | 5.8  | 6        | 6.2      | V           |
| CT pin high level voltage         | $V_{CTH}$   | -                               | 3.4  | 3.6      | 3.8      | V           |
| CT pin low level voltage          | $V_{CTL}$   | -                               | 1.4  | 1.6      | 1.8      | V           |
| CT pin charge current             | $I_{CT1}$   | -                               | 1.8  | 2.2      | 2.6      | uA          |
| CT pin discharge current          | $I_{CT2}$   | -                               | 0.18 | 0.22     | 0.26     | uA          |
| CT charge/discharge current ratio | $R_{CT}$    | $R_{CD} = I_{CT1} / I_{CT2}$    | 8    | 10       | 12       | -           |
| OUT output L saturation voltage   | $V_{OL}$    | $I_O=200mA$                     | -    | 0.1      | 0.2      | V           |
| OUT output H saturation voltage   | $V_{OH}$    | $I_O=200 mA, V_M=V_{CC}$        | -    | 0.6      | 0.8      | V           |
| Hall input sensitivity            | $V_{HN}$    | Including offset and hysteresis | -    | $\pm 10$ | $\pm 20$ | mV          |
| FG output pin L voltage           | $V_{FG}$    | $I_{FG}=5mA$                    | -    | 0.2      | 0.3      | V           |
| FG output pin leak current        | $I_{FGL}$   | $V_{FG}=7V$                     | -    |          | 30       | uA          |
| Over current protection voltage   | $V_{OLMAX}$ | -                               | -    | 1.5      | -        | V           |
| Overheat protection temperature   | $T_{SD}$    | *Design guarantee value         | -    | 170      | -        | $^{\circ}C$ |

Table 4. Electrical Characteristics

**Truth Table**

| PWM | VTH (RMI) | FD  |
|-----|-----------|-----|
| H   | L         | L   |
| H   | H         | OFF |
| L   | X         | OFF |

VTH (RMI)-L:  $V_{TH} < CPWM$  or  $RMI < CPWM$

| CT | IN- | IN+ | FO | OUT1 | OUT2 | FG  | Mode                 |
|----|-----|-----|----|------|------|-----|----------------------|
| L  | H   | L   | L  | H    | L    | L   | Running-drive        |
|    | L   | H   |    | L    | H    | OFF |                      |
|    | H   | L   | H  | OFF  | L    | L   | Running-regeneration |
|    | L   | H   |    | L    | OFF  | OFF |                      |
| H  | H   | L   | X  | H    | OFF  | L   | Lock protection      |
|    | L   | H   |    | OFF  | H    | OFF |                      |

FO-L: FO&lt;CPWM ; FO-H: FO&gt;CPWM

Table 5. Truth Table

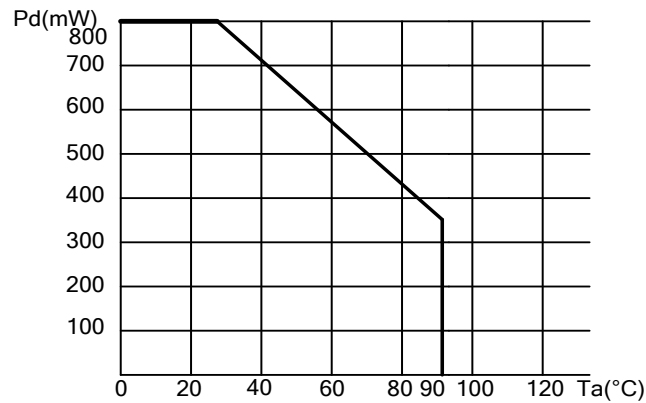
**Power Dissipation Curve**


Figure 3. Power Dissipation Curve(SSOP-20)

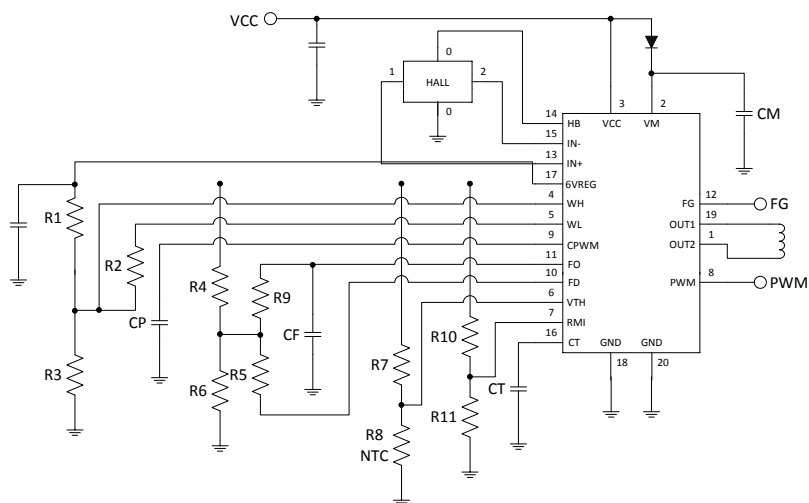
**Typical Application**


Figure 4. Typical Application

## Function Description

### PWM and Thermistor Speed Control

For advanced CPU cooler fans, SDC11170 provides speed control by temperature and external PWM signal at the same time. Using the thermistor to determine VTH pin voltage by temperature and use RMI pin voltage to set minimum temperature for speed control. Set the L level of triangular wave to set maximum temperature and H level of triangular wave to set the minimum pulse width for temperature speed control. Internal circuit generates a pulse width signal by comparing VTH and RMI with triangular wave, and mixes it with external PWM signal

at FD pin.

The RC filter transfers the mixed signal at FD pin to a dc voltage at FO pin. External resistors are used to define the voltage range of the FO pin. Since the final pulse width is obtained by comparing the voltage of FO with triangular wave, the voltage range of FO define the minimum pulse width at the output stage, and the frequency on the output stage is the same of the triangular wave.

To avoid nonlinearity in speed characteristics, the resistor in RC filter should have a much larger resistance than those defining the voltage range.

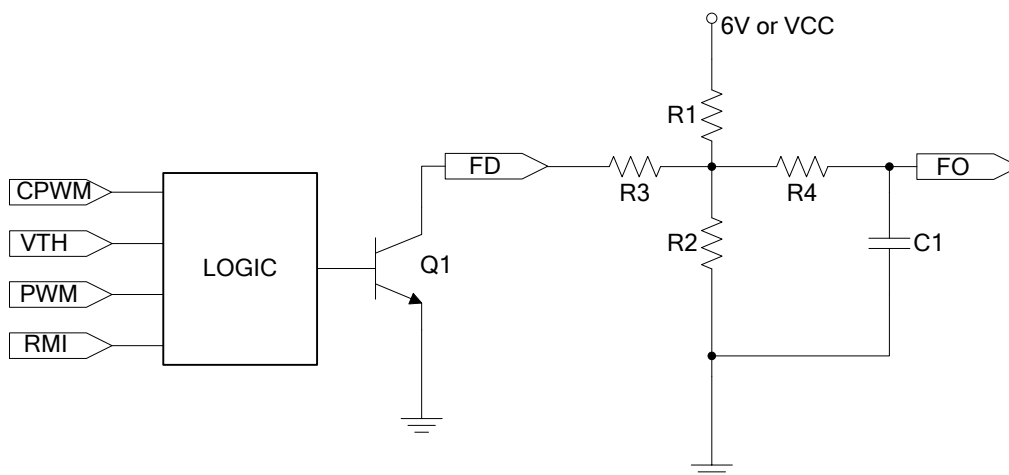


Figure 5.

The control method is filed under patent pending.

### Driver Architecture

In prior art, a protection diode is introduced to prevent the damage from the power reverse connection. However, the protection diode will cause a voltage drop on the

supply voltage. The voltage drop from power supply to output pin is the sum of  $V_F$  (Voltage drop of the protection diode),  $V_{PSAT}$  (saturation voltage of the PNP transistor driving the upper output transistor) and  $V_{BE}$  (of the upper output transistor), normally it is about 1.7V, and about  $0.8V \cdot I_{OUT}$  become the IC's power dissipation.

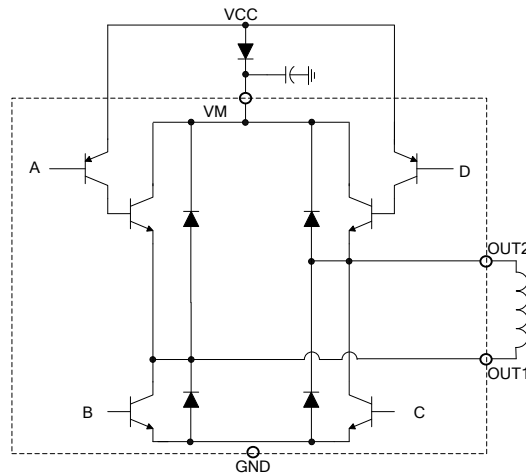


Figure 6.

SDC11170 adapt a new architecture, placing the protection diode between power supply and VM pin. With VCC directly connected to power supply, the voltage drop from power supply to output pin has been reduced to about 1.1V, and only  $0.2V \cdot I_{OUT}$  contribute to the IC's power dissipation. This innovation made a boost to the IC's continuous output current, without increasing the cost of the package.

This architecture is filed under patent pending.

### Protections

Lock-shutdown and auto-restart use a capacitor connecting to CT pin to decide lock detection time and lock protection time. Charged by a 2.2uA current, the capacitor will try to reach the voltage of 3.6V and trigger

lock-shutdown. However, a hall phase change will cause a complete discharge of the capacitor. In normal operation, the capacitor will be discharged frequently and the voltage of CT will not reach 1.6V.

If the fan is stopped by force, lock-shutdown will be triggered when the voltage of CT reaches 3.6V, shut the lower transistors down to prevent overheating. Then the capacitor will be discharged by a 0.22uA current, until the voltage of CT reaches 1.6V and enter restart mode.

During restart, if VM pin voltage is higher than 6V, the FD pin pulse width will be 0.5 times of the original pulse width in order to achieve a low temperature rise in lock condition (shown in the illustration below); if not, the pulse width will be normal.

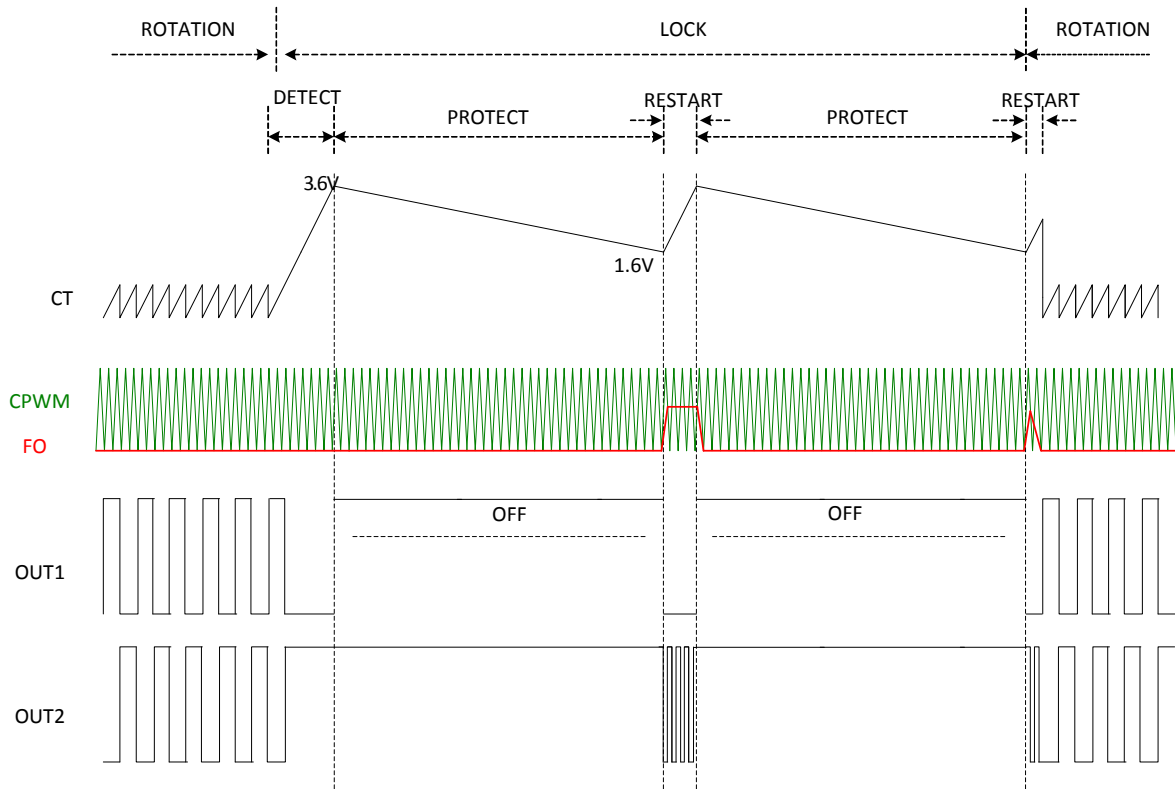


Figure 7.

Thermal-shutdown protection will shutdown the chip if the junction temperature reaches 170°C, it has about 30°C hysteresis, that is, when the junction temperature reduced to 140°C, the chip will operate again.

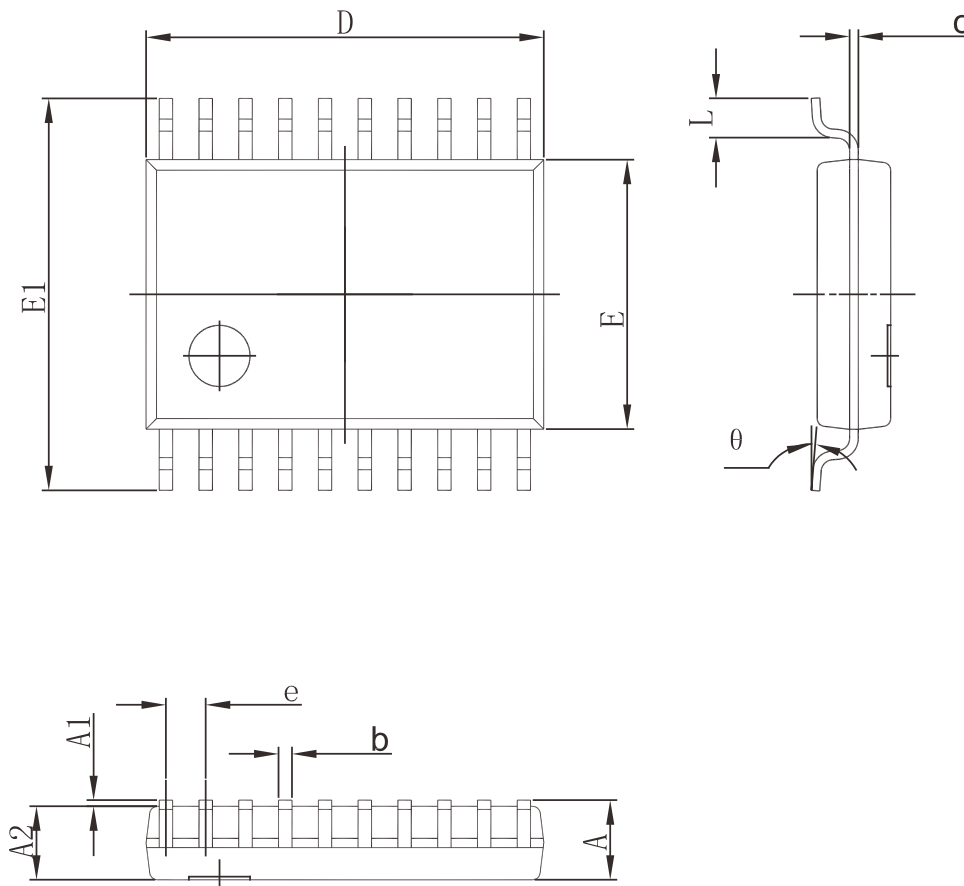
Over current protection (OCP) circuit will shutdown the upper transistor if the output L saturation voltage reaches 1.5V, this will only happen if the output current exceeds 1.2A. When this happens, the current in the coil will decrease, and the saturation voltage will drop. When the saturation voltage drops to 1V or below, the OCP circuit will release control and the output stage will go back to normal operation.

The OCP detecting circuitry is filed under patent pending.

Internal VCC protection diode was incorporated, if a -12V voltage is given to VCC, the reverse current is normally smaller than 10mA and will not cause damage to the chip. However, VM pin have direct connections to the collectors of NPN transistors, so it is recommended to use an external diode in order to achieve a full polarity protection.

Thermistor trip protection activates when the voltage of  $V_{TH}$  approach 6V or above, so it is suggested to use  $V_{CC}$  as the power supply of the external thermistor.



**Package Dimension**  
**SSOP-20**


| Symbol | Dimensions In Millimeters |       | Dimensions In Inches |       |
|--------|---------------------------|-------|----------------------|-------|
|        | Min                       | Max   | Min                  | Max   |
| A      | --                        | 1.450 | --                   | 0.057 |
| A1     | 0.050                     | 0.200 | 0.002                | 0.008 |
| A2     | 1.150                     | 1.250 | 0.045                | 0.049 |
| b      | 0.200                     | 0.310 | 0.008                | 0.013 |
| c      | 0.090                     | 0.200 | 0.004                | 0.008 |
| D      | 6.300                     | 6.700 | 0.248                | 0.264 |
| e      | 0.65(BSC)                 |       | 0.026(BSC)           |       |
| E1     | 6.200                     | 6.600 | 0.244                | 0.260 |
| E      | 4.200                     | 4.500 | 0.169                | 0.177 |
| L      | 0.450                     | 0.750 | 0.018                | 0.030 |
| θ      | 0°                        | 8°    | 0°                   | 8°    |

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